1. General description

PNP/PNP general-purpose transistor pair in a very small Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: BC846BS NPN/PNP complement: BC846BPN

2. Features and benefits

- Low collector capacitance
- Low collector-emitter saturation voltage
- Closely matched current gain
- · Reduces number of components and board space
- No mutual interference between the transistors
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	-65	V
I _C	collector current		-	-	-100	mA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}$	200	290	450	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	6 5 4	
3	C2	collector TR2		(TR1)
4	E2	emitter TR2		
5	B2	base TR2	□1 □2 □3	E1 B1 C2
6	C1	collector TR1	TSSOP6 (SOT363)	sym018



65 V, 100 mA PNP/PNP general-purpose transistor

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage						
	Name	Description	Version					
BC856BS-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363					

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BC856BS-Q	%E6

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

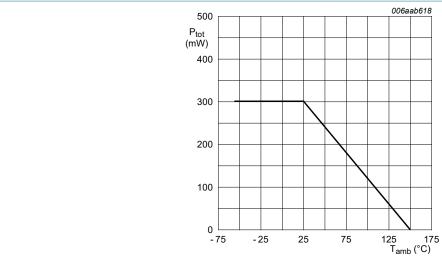
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or		'	_	'	
V_{CBO}	collector-base voltage	open emitter		-	-80	V
V_{CEO}	collector-emitter voltage	open base		-	-65	V
V_{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-200	mA
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device	'		'			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

65 V, 100 mA PNP/PNP general-purpose transistor



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

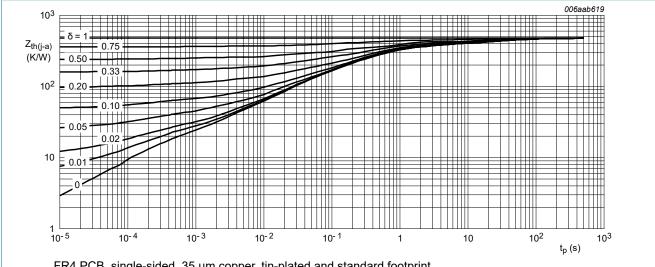
Fig. 1. Per device: Power derating curve

Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		I	Min	Тур	Max	Unit
Per transisto	or		•					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	-	625	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	-	230	K/W
Per device			•	,		•		
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

65 V, 100 mA PNP/PNP general-purpose transistor

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor					
I _{CBO}	collector-base cut-off	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-15	nA
	current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -6 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -10 μA; T _{amb} = 25 °C	-	270	-	
		V _{CE} = -5 V; I _C = -2 mA	200	290	450	
V _{CEsat}	collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-55	-100	mV
	saturation voltage	I_C = -100 mA; I_B = -5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-200	-300	mV
V _{BEsat}	base-emitter saturation	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-755	-850	mV
voltage	voltage	I_C = -100 mA; I_B = -5 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-900	-	mV
V _{BE}	base-emitter voltage	V _{CE} = -5 V; I _C = -2 mA; T _{amb} = 25 °C	-600	-650	-750	mV
		V _{CE} = -5 V; I _C = -10 mA; T _{amb} = 25 °C	-	-	-820	mV
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	2.3	-	pF
C _e	emitter capacitance	V _{EB} = -0.5 V; I _C = 0 A; i _c = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	10	-	pF
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C	100	-	-	MHz
NF	noise figure	V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 10 Hz to 15.7 kHz; T_{amb} = 25 °C	-	1.6	-	dB
		V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 1 kHz; B = 200 Hz; T_{amb} = 25 °C	-	2.9	-	dB

-0.20 I_C (A)

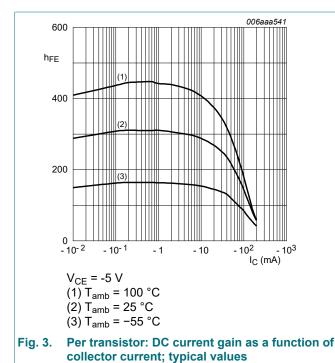
-0.16

-0.12

- 0.08

- 0.04

-2



T_{amb} = 25 °C

Fig. 4. Per transistor: Collector current as a function of collector-emitter voltage; typical values

- 4

-8 -10 V_{CE} (V)

006aaa540

- 0.75

- 0.5

- 0.25

- 6

65 V, 100 mA PNP/PNP general-purpose transistor

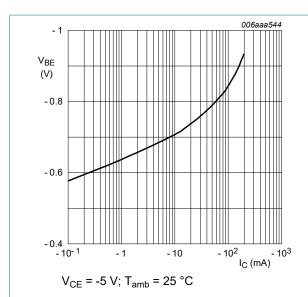
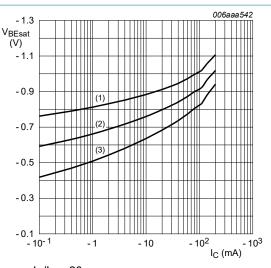
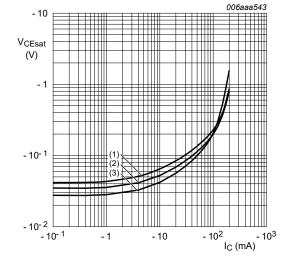


Fig. 5. Per transistor: Base-emitter voltage as a function of collector current; typical values



 $I_C/I_B = 20$ (1) $T_{amb} = -55$ °C (2) $T_{amb} = 25$ °C (3) $T_{amb} = 100$ °C

Fig. 6. Per transistor: Base-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 20$ (1) $T_{amb} = 100 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = -55 \,^{\circ}C$



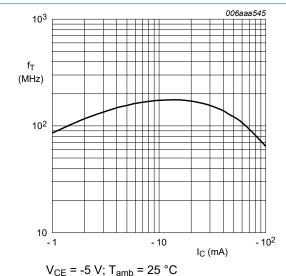


Fig. 8. Per transistor: Transition frequency as a function of collector current; typical values

65 V, 100 mA PNP/PNP general-purpose transistor

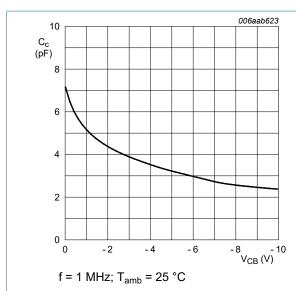


Fig. 9. Per transistor: Collector capacitance as a function of collector-base voltage; typical values

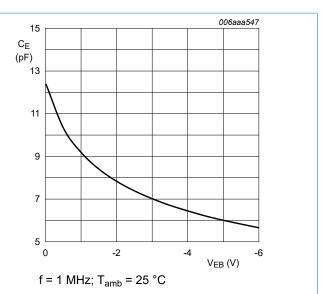


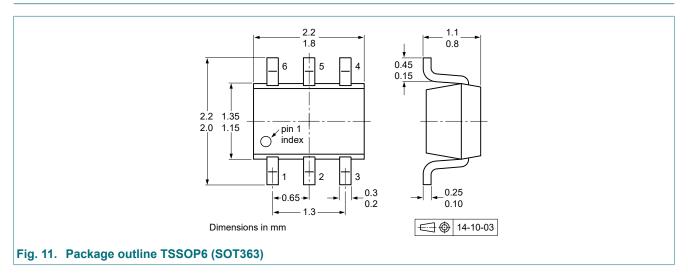
Fig. 10. Per transistor: Emitter capacitance as a function of emitter-base voltage; typical values

11. Test information

Quality information

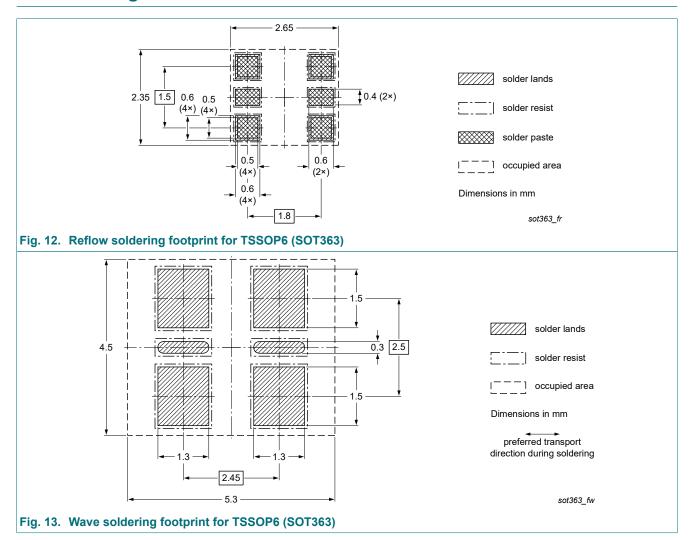
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



65 V, 100 mA PNP/PNP general-purpose transistor

13. Soldering



65 V, 100 mA PNP/PNP general-purpose transistor

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC856BS-Q v.1	20231109	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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BC856BS-C

65 V, 100 mA PNP/PNP general-purpose transistor

Contents

1.	General description	1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	1
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	. 2
	Thermal characteristics	
10.	Characteristics	4
11.	Test information	6
	Package outline	
	Soldering	
	Revision history	
	Legal information	

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